

**AMENDMENTS TO THE CLAIMS**

1. (Currently Amended) An X-ray exposure apparatus comprising:

two X-ray mirrors containing a material having an absorption edge only in a range of a wavelength other than 0.45 nm through 0.7 nm for X-rays,

said X-ray mirrors receiving an X-ray having an angle of oblique incidence of no more than 1.5°, wherein

an X-ray received by said X-ray mirrors is outputted having a first angle and a second angle, wherein the first angle is greater than the second angle,

a first of said X-ray mirrors collects ~~an~~ the X-ray in a direction in which the X-ray is outputted at the first angle ~~outgoing from said X-ray mirrors~~, and

a second of said X-ray mirrors increases an area of a region illuminable by X-rays outgoing from said X-ray mirrors in a direction in which the X-ray is outputted at the second angle.

2. (Original) The X-ray exposure apparatus according to claim 1, wherein said X-rays are included in radiation outgoing from a synchrotron radiation source.

Claim 3 (Cancelled)

4. (Previously Presented) The X-ray exposure apparatus according to claim 1, wherein said X-ray mirrors contain a single type of mirror material selected from a group consisting of

beryllium, titanium, silver, ruthenium, rhodium and palladium, nitrides, carbides and borides of these, diamond, diamond-like carbon and boron nitride.

Claims 5-10 (Cancelled)

11. (Original) The X-ray exposure apparatus according to claim 1 further comprising an X-ray mask, wherein said X-ray mask includes a membrane and an X-ray absorber formed on said membrane, and

said membrane contains a single species selected from a group consisting of diamond, diamond-like carbon, boron nitride and beryllium.

12. (Original) The X-ray exposure apparatus according to claim 1 further comprising an X-ray mask, wherein said X-ray mask includes a membrane and an X-ray absorber formed on said membrane,

said membrane contains a material having an absorption edge only in at least either one of a wavelength region of less than 0.45 nm and a wavelength region exceeding 0.7 nm as to X-rays, and

said X-ray absorber contains a material having an absorption edge in a wavelength region of at least 0.6 nm and less than 0.85 nm.

Claims 13-23 (Cancelled)

24. (Currently Amended) An X-ray exposure method comprising:

an X-ray incidence step of making X-rays incident upon two X-ray mirrors containing a material having an absorption edge only in a range of wavelength other than 0.45 nm through 0.7 nm for X-rays, said X-ray mirrors receiving an X-ray having an angle of oblique incidence ~~[[on]]~~ of no more than ~~[[15]]~~ 1.5°; wherein

an X-ray received by said X-ray mirrors is outputted having a first angle and a second angle, wherein the first angle is greater than the second angle,

a first of said X-ray mirrors collects ~~an~~ the X-ray in a direction in which the X-ray is outputted at the first angle ~~outgoing from said X-ray mirrors~~, and

a second of said X-ray mirrors increases an area of a region illuminable by X-rays outgoing from said X-ray mirrors in a direction in which the X-ray is outputted at the second angle.

25. (Original) The X-ray exposure method according to claim 24, further comprising an X-ray outgoing step of making said X-rays outgo from a synchrotron radiation source.

Claim 26 (Cancelled)

27. (Previously Presented) The X-ray exposure method according to claim 24, wherein said X-ray mirrors contain a single type of mirror material selected from a group consisting of beryllium, titanium, silver, ruthenium, rhodium and palladium, nitrides, carbides and borides of these, diamond, diamond-like carbon and boron nitride.

Claims 28-33 (Cancelled)

34. (Original) The X-ray exposure method according to claim 24 employing an X-ray mask, wherein said X-ray mask includes a membrane and an X-ray absorber formed on said membrane, and

said membrane contains a single species selected from a group consisting of diamond, diamond-like carbon, boron nitride and beryllium.

35. (Original) The X-ray exposure method according to claim 24 employing an X-ray mask, wherein said X-ray mask includes a membrane and an X-ray absorber formed on said membrane,

said membrane contains a material having an absorption edge only in at least either one of a wavelength region of less than 0.45 nm and a wavelength region exceeding 0.7 nm as to X-rays, and

said X-ray absorber contains a material having an absorption edge in a wavelength region of at least 0.6 nm and less than 0.85 nm.

Claims 36-38 (Cancelled)

39. (Original) A semiconductor device manufactured with the X-ray exposure method according to claim 24.

40. (Currently Amended) A synchrotron radiation apparatus comprising a synchrotron radiation source and two X-ray mirrors upon which radiation outgoing from said synchrotron radiation source is incident,

said two X-ray mirrors containing a material having an absorption edge only in a range of wavelength other than 0.45 nm through 0.7 nm for X-rays, and receiving an X-ray having an angle of oblique incidence ~~[[on]]~~ of no more than [[15]] 1.5°, wherein

an X-ray received by said X-ray mirrors is outputted having a first angle and a second angle, wherein the first angle is greater than the second angle,

a first of said X-ray mirrors collects ~~an~~ the X-ray in a direction in which the X-ray is outputted at the first angle ~~outgoing from said X-ray mirrors~~, and

a second of said X-ray mirrors increases an area of a region illuminable by X-rays outgoing from said X-ray mirrors in a direction in which the X-ray is outputted at the second angle.

Claim 41 (Cancelled)

42. (Currently Amended) A synchrotron radiation method employing a synchrotron radiation apparatus including a synchrotron radiation source and two X-ray mirrors upon which radiation outgoing from said synchrotron radiation source is incident, said two X-ray mirrors containing a material having an absorption edge only in a range of a wavelength other than 0.45 nm through 0.7 nm for X-rays, the method comprising:

a radiation incidence step of making incident upon said two X-ray mirrors an X-ray outgoing from the synchrotron radiation source and having an angle of oblique incidence of no more than 1.5°; and

an exposure step of performing exposure with X-rays outgoing from said X-ray mirrors, wherein

an X-ray received by said X-ray mirrors is outputted having a first angle and a second angle, wherein the first angle is greater than the second angle,

a first of said X-ray mirrors collects ~~an~~ the X-ray in a direction in which the X-ray is outputted at the first angle outgoing from said X-ray mirrors, and

a second of said X-ray mirrors increases an area of a region illuminable by X-rays outgoing from said X-ray mirrors in a direction in which the X-ray is outputted at the second angle.

Claims 43-45 (Cancelled)

46. (Previously Presented) The X-ray exposure apparatus of claim 1, further comprising means altering a peak wavelength of said light emanating from said X ray mirrors while maintaining a direction of said light emanating from said X ray mirrors.

47. (Previously Presented) The X-ray exposure apparatus of claim 1, further comprising means altering a peak wavelength of said light emanating from said X-ray mirrors while maintaining an optical axis of said light emanating from said X-ray mirrors.

48. (Previously Presented) The X-ray exposure method of claim 24, further comprising the step of altering a peak wavelength of said X-ray emanating from said X-ray mirrors while maintaining a direction of said X-ray emanating from said X-ray mirrors.

49. (Previously Presented) The X-ray exposure method of claim 24, further comprising the step of altering a peak wavelength of said X-ray emanating from said X-ray mirrors while maintaining an optical axis of said X-ray emanating from said X-ray mirrors.

50. (Previously Presented) An X-ray exposure apparatus, comprising:

a first stage X-ray mirror, and

a second stage X-ray mirror, wherein

$\alpha$  represents an angle of oblique incidence of an X-ray incident on said first stage X-ray mirror and said second stage X-ray mirror,

L represents a distance between said first and second stage X-ray mirrors, as seen along an x-axis corresponding to a direction of the X-ray incident on said first stage X-ray mirror,

D represents a distance from incidence of an optical axis of the X-ray incident on said first stage X-ray mirror to said second stage X-ray mirror, and

said  $\alpha$  and L are changed to satisfy a relationship  $D = L \times \tan(2\alpha)$ , whereby respective optical axes of X-rays have substantially identical directions, and a spectral distribution of an X-ray outgoing from said second stage is changed.

51. (Previously Presented) An X-ray exposure apparatus, comprising:

a first stage X-ray mirror,  
a second stage X-ray mirror, and  
a third stage X-ray mirror, wherein

$\alpha$  represents an angle of oblique incidence of an X-ray incident on said first stage X-ray mirror and said third stage X-ray mirror,

$2\alpha$  represents an angle of oblique incidence of an X-ray incident on said second stage X-ray mirror,

L represents a distance between said first and second stage X-ray mirrors and a distance between said second and third stage X-ray mirrors, as seen along an x-axis corresponding to a direction of the X-ray incident on said first stage X-ray mirror,

D represents a distance from incidence of an optical axis of the X-ray incident on said first stage X-ray mirror to said second stage X-ray mirror, and

said  $\alpha$  and L are changed to satisfy a relationship  $D = L \times \tan(2\alpha)$ , whereby respective optical axes of X-rays have substantially identical directions, and a spectral distribution of an X-ray outgoing from said third stage is changed.

52. (Previously Presented) An X-ray exposure apparatus, comprising:

a first stage X-ray mirror,  
a second stage X-ray mirror,  
a third stage X-ray mirror, and  
a fourth stage X-ray mirror, wherein

$\alpha$  represents an angle of oblique incidence of an X-ray incident on each of said first, second, third and fourth stage X-ray mirrors,



L represents a distance between said first and second stage X-ray mirrors and a distance between said third and fourth stage X-ray mirrors, as seen along an x-axis corresponding to a direction of the X-ray incident on said first stage X-ray mirror,

D represents a distance from incidence of an optical axis of the X-ray incident on said first stage X-ray mirror to said third and fourth stage X-ray mirrors, and

said  $\alpha$  and L are changed to satisfy a relationship  $D = L \times \tan(2\alpha)$ , whereby respective optical axes of X-rays have substantially identical directions, and a spectral distribution of an X-ray outgoing from said fourth stage is changed.

53. (Previously Presented) An X-ray exposure apparatus, comprising:

a first stage X-ray mirror,

a second stage X-ray mirror,

a third stage X-ray mirror, and

a fourth stage X-ray mirror, wherein

$\alpha$  represents an angle of oblique incidence of an X-ray incident on each of said first and fourth stage X-ray mirrors,

$\beta$  represents an angle of oblique incidence of an X-ray incident on each of said second and third stage X-ray mirrors,

$L\alpha$  represents a distance between said first and second stage X-ray mirrors and a distance between said third and fourth stage X-ray mirrors, as seen along an x-axis corresponding to a direction of the X-ray incident on said first stage X-ray mirror,

$L\beta$  represents a distance between said second and third stage X-ray mirrors, as seen along said x-axis,

D represents a distance between said second and third stage X-ray mirrors, as seen along a y-axis corresponding to a direction perpendicular to said x-axis, and

said  $\alpha$ ,  $\beta$ ,  $L\alpha$  and  $L\beta$  are changed to satisfy a relationship  $D = 2 \times L\alpha \times \tan(2\alpha) = L\beta \times \tan(\beta - \alpha)$ , whereby  
respective optical axes of X-rays have substantially identical directions, and  
a spectral distribution of an X-ray outgoing from said fourth stage is changed.